■ Lighting Color

• Blue • Red

LNJ115W85RA1

Hight Bright Surface Mounting Chip LED

TSS-2 Type

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol Rating		Unit
Power dissipation	P_{D}	65	mW
Forward current	I_{F}	15	mA
Pulse forward current *	I_{FP}	55	mA
Reverse voltage	V _R	5	V
Operating ambient temperature	T _{opr}	-30 to +85	°C
Storage temperature	T _{stg}	-40 to +100	°C

Note) *: The condition of I_{FP} is duty 10%, Pulse width 1 msec.

• Red

Parameter	Symbol	Rating	Unit	
Power dissipation	P _D	55	mW	
Forward current	I_{F}	20	mA	
Pulse forward current *	I _{FP}	60	mA	
Reverse voltage	V_R	4	V	
Operating ambient temperature	T _{opr}	-30 to +85	°C	
Storage temperature	T _{stg}	-40 to +100	°C	

Note) *: The condition of I_{FP} is duty 10%, Pulse width 1 msec.

■ Electro-Optical Characteristics $T_a = 25^{\circ}C\pm3^{\circ}C$

• Blue

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Luminous intensity *	I _O	$I_F = 5 \text{ mA}$	5.0	12.0	41.8	mcd
Reverse current	I _R	$V_R = 5 \text{ V}$			100	μΑ
Forward voltage	$V_{\rm F}$	$I_F = 5 \text{ mA}$		2.90	3.20	V
Peak emission wavelength	λ_{P}	$I_F = 5 \text{ mA}$		465		nm
Dominant emission wavelength	$\lambda_{ m d}$	$I_F = 5 \text{ mA}$	462	470	478	nm
Spectral half band width	Δλ	$I_F = 5 \text{ mA}$		20		nm

Note) *: Measurement tolerance: ±20%

• Red

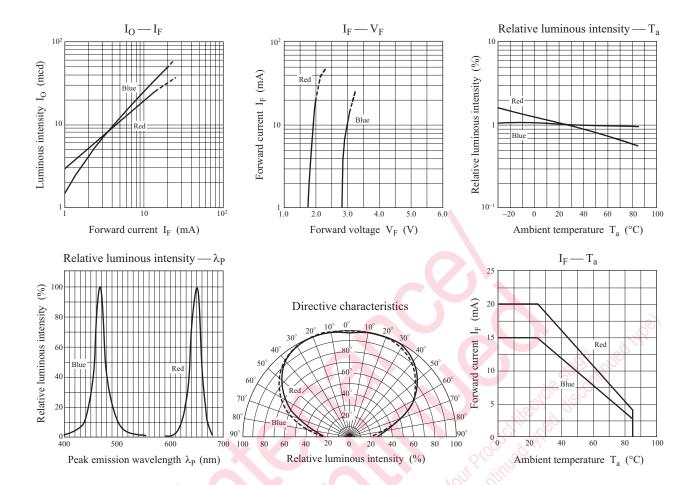
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Luminous intensity *	I _O	$I_F = 10 \text{ mA}$	12.0	24.0	60.8	mcd
Reverse current	I_R	$V_R = 4 V$			100	μА
Forward voltage	V _F	$I_F = 10 \text{ mA}$		1.92	2.50	V
Peak emission wavelength	λ_{P}	$I_F = 10 \text{ mA}$		645		nm
Dominant emission wavelength	λ_{d}	$I_F = 10 \text{ mA}$	620	630	640	nm
Spectral half band width	Δλ	$I_F = 10 \text{ mA}$		22		nm

Note) *: Measurement tolerance: ±20%

Forward voltage	$V_{\rm F}$	$I_F = 10 \text{ mA}$		1.92	2.50	V
Peak emission wavelength	λ_{P}	$I_F = 10 \text{ mA}$		645		nm
Dominant emission wavelength	λ_{d}	$I_F = 10 \text{ mA}$	620	630	640	nm
Spectral half band width	Δλ	$I_F = 10 \text{ mA}$		22		nm

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Panasonic

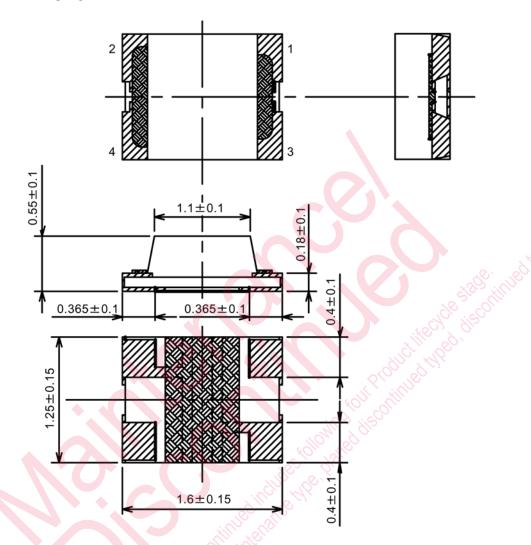


2 Ver. AEK

Panasonic LNJ115W85RA1

■ Package (Unit: mm)

KLTFTN4K1540



- Pin name
 - 1, 3: Anode
 - 2, 4: Cathode

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